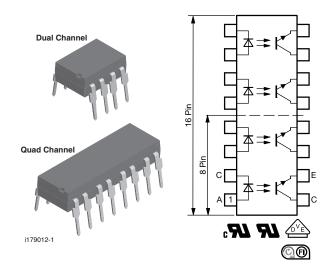


Vishay Semiconductors

RoHS

COMPLIANT

Optocoupler, Phototransistor Output, (Dual, Quad Channel)



_ .

channel) package.

FEATURES

- Extra low coupling capacity typical 0.2 pF
- High common mode rejection
- Low temperature coefficient of CTR
- Rated impulse voltage (transient overvoltage)
 V_{IOTM} = 10 kV peak



- Thickness through insulation ≥ 0.4 mm
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

AGENCY APPROVALS

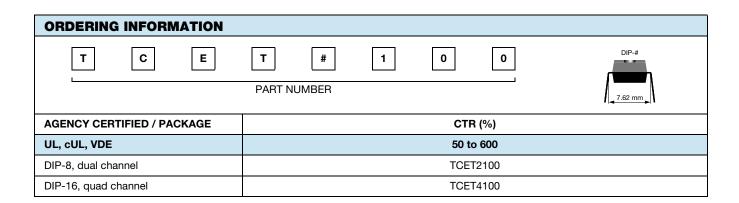
- UL
- cUL
- DIN EN 60747-5-5 (VDE 0884)
- FIMKO

LINKS TO ADDITIONAL RESOURCES



DESCRIPTION

The TCET2100, TCET4100 consists of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode, available in 8 pin (dual channel) and 16 pin (quad





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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT							
Reverse voltage		V _R	6	V			
Forward current		I _F	60	mA			
Forward surge current	t _p ≤ 10 μs	I _{FSM}	1.5	А			
Power dissipation		P _{diss}	100	mW			
Junction temperature		Tj	125	°C			
OUTPUT							
Collector emitter voltage		V_{CEO}	70	V			
Emitter collector voltage		V _{ECO}	7	V			
Collector current		Ic	50	mA			
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I _{CM}	100	mA			
Power dissipation		P _{diss}	150	mW			
Junction temperature		Tj	125	°C			
COUPLER							
Total power dissipation		P _{tot}	250	mW			
Operating ambient temperature range		T _{amb}	-55 to +100	°C			
Storage temperature range		T _{stg}	-55 to +150	°C			
Soldering temperature (1)	2 mm from case, t ≤ 10 s	T _{sld}	260	°C			

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
 implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
 maximum ratings for extended periods of the time can adversely affect reliability.
- $^{(1)}$ Refer to wave profile for soldering conditions for through hole devices.

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT							
Forward voltage	$I_F = \pm 50 \text{ mA}$	V_{F}	-	1.25	1.6	V	
Junction capacitance	acitance $V_R = 0 V, f = 1 MHz$		-	50	-	pF	
OUTPUT							
Collector emitter voltage	I _C = 1 mA	V_{CEO}	70	-	-	V	
Emitter collector voltage	I _E = 100 μA	V_{ECO}	7	-	-	V	
Collector emitter cut-off current	$V_{CE} = 20 \text{ V}, I_F = 0, E = 0$	I _{CEO}	-	10	100	nA	
COUPLER							
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 1 \text{ mA}$	V _{CEsat}	-	-	0.3	V	
Cut-off frequency	$V_{CE} = 5 \text{ V}, I_{F} = 10 \text{ mA}, R_{L} = 100 \Omega$	f _c	-	110	-	kHz	
Coupling capacitance	f = 1 MHz	C_k	-	0.3	-	pF	

Note

Minimum and maximum values were tested requirements. Typical values are characteristics of the device and are the result of engineering
evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
I _C /I _F	$V_{CE} = 5 \text{ V}, I_{F} = 5 \text{ mA}$	CTR	50	-	600	%



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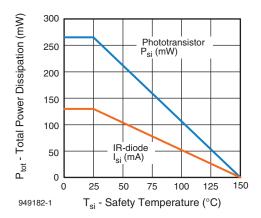


Fig. 1 - Derating Diagram

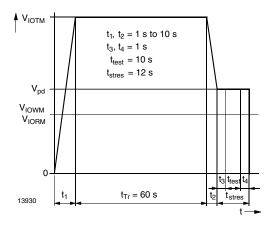


Fig. 2 - Test Pulse Diagram for Sample Test According to DIN EN 60747-5-5/DIN EN 60747-; IEC60747

SWITCHING CHARACTERISTICS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Delay time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega, \text{ (see Fig. 3)}$	t _d	-	3	-	μs	
Rise time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega, \text{ (see Fig. 3)}$	t _r	=	3	-	μs	
Turn-on time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega, \text{ (see Fig. 3)}$	t _{on}	=	6	-	μs	
Storage time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega, \text{ (see Fig. 3)}$	t _s	-	0.3	-	μs	
Fall time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega, \text{ (see Fig. 3)}$	t _f	=	4.7	-	μs	
Turn-off time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega, \text{ (see Fig. 3)}$	t _{off}	-	5	-	μs	
Turn-on time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega, \text{ (see Fig. 4)}$	t _{on}	-	9	-	μs	
Turn-off time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega, \text{ (see Fig. 4)}$	t _{off}	-	10	-	μs	

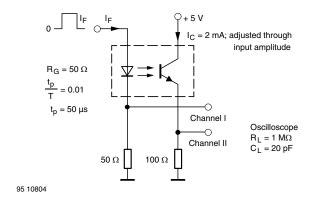


Fig. 3 - Test Circuit, Non-Saturated Operation

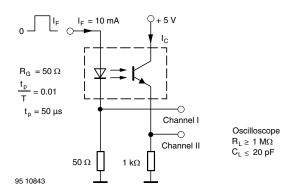


Fig. 4 - Test Circuit, Saturated Operation



1.424

 kV_{peak}

 V_{pd}

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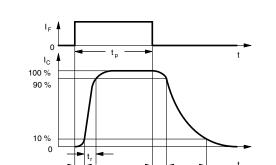


Fig. 5 - Switching Times

Storage time Fall time

Turn-off time

96 11698

Pulse duration

Delay time Rise time

Turn-on time

Partial discharge test voltage - lot test (sample test)

SAFETY AND INSULATION RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
Climatic classification	According to IEC 68 part 1		55 / 100 / 21				
Comparative tracking index		CTI	175				
Maximum rated withstanding isolation voltage	t = 1 min	V _{ISO}	4420	V _{RMS}			
Maximum transient isolation voltage		V _{IOTM}	10 000	V _{peak}			
Maximum repetitive peak isolation voltage		V _{IORM}	890	V _{peak}			
Isolation resistance	V _{IO} = 500 V, T _{amb} = 25 °C	R _{IO}	≥ 10 ¹²	Ω			
	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	≥ 10 ¹¹	Ω			
	V _{IO} = 500 V, T _{amb} = 150 °C (construction test only)	R _{IO}	≥ 10 ⁹	Ω			
Output safety power		P _{SO}	400	mW			
Input safety current		I _{SI}	275	mA			
Safety temperature		T _S	175	°C			
Creepage distance			≥ 7	mm			
Clearance distance			≥ 7	mm			
Insulation thickness		DTI	≥ 0.4	mm			
Partial discharge test voltage - routine test	100 %, t _{test} = 1 s	V _{nd}	1.669	kV _{nea}			

Note

• As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

 $t_{Tr} = 60 \text{ s}, t_{test} = 10 \text{ s}, (see Fig. 2)$

1000

100

10

IF - Forward Current (mA)

96 11862

CTR_{rel} - Relative Current Transfer Ratio

2.0

1.5

1.0

0.5

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TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

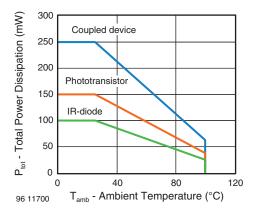


Fig. 6 - Total Power Dissipation vs. Ambient Temperature



Fig. 7 - Forward Current vs. Forward Voltage

0.8

1.2

V_F - Forward Voltage (V)

2.0

 $V_{CE} = 5 V$ $I_{F} = 5 mA$



Fig. 8 - Relative Current Transfer Ratio vs. Ambient Temperature

T_{amb} - Ambient Temperature (°C)

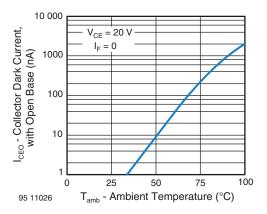


Fig. 9 - Collector Dark Current vs. Ambient Temperature

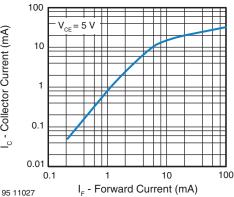


Fig. 10 - Collector Current vs. Forward Current

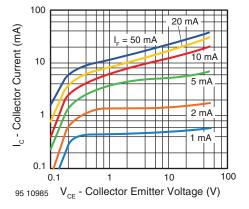


Fig. 11 - Collector Current vs. Collector Emitter Voltage

For technical questions, contact: optocouplera



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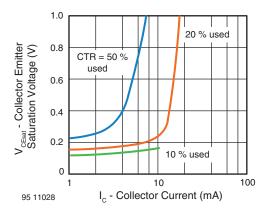


Fig. 12 - Collector Emitter Saturation Voltage vs. Collector Current

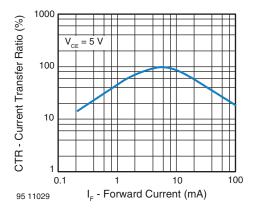


Fig. 13 - Current Transfer Ratio vs. Forward Current

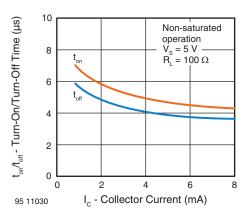


Fig. 14 - Turn-on/off Time vs. Collector Current

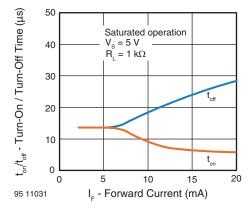
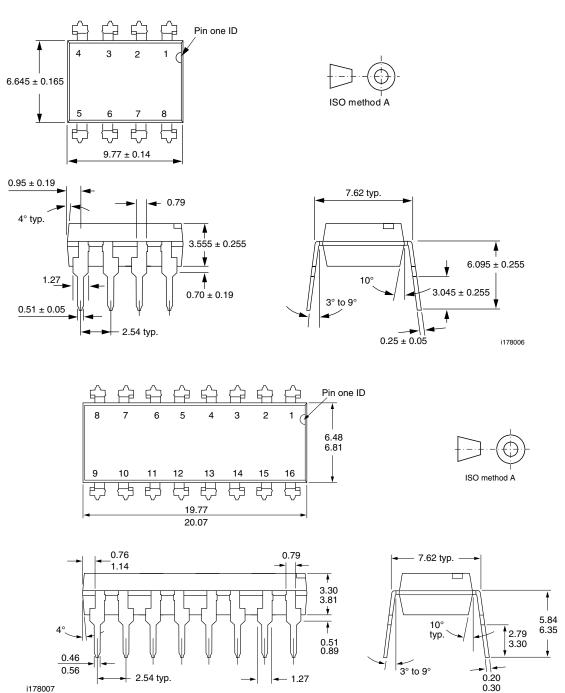


Fig. 15 - Turn-On / Turn-Off Time vs. Forward Current

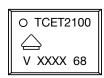


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PACKAGE DIMENSIONS in millimeters



PACKAGE MARKING (example)



Note

• XXXX = LMC (lot marking code)



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